

# Quad 2-Channel Analog Multiplexer/Demultiplexer

## MC14551B

The MC14551B is a digitally-controlled analog switch. This device implements a 4PDT solid state switch with low ON impedance and very low OFF Leakage current. Control of analog signals up to the complete supply voltage range can be achieved.

### Features

- Triple Diode Protection on All Control Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Analog Voltage Range ( $V_{DD} - V_{EE}$ ) = 3.0 to 18 V  
Note:  $V_{EE}$  must be  $\leq V_{SS}$
- Linearized Transfer Characteristics
- Low Noise – 12 nV $\sqrt{\text{Cycle}}$ ,  $f \geq 1.0$  kHz typical
- For Low  $R_{ON}$ , Use The HC4051, HC4052, or HC4053 High-Speed CMOS Devices
- Switch Function is Break Before Make
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

### MAXIMUM RATINGS

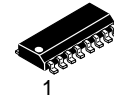
Parameter	Symbol	Value	Unit
DC Supply Voltage Range (Referenced to $V_{EE}$ , $V_{SS} \geq V_{EE}$ )	$V_{DD}$	-0.5 to + 18.0	V
Input or Output Voltage (DC or Transient) (Referenced to $V_{SS}$ for Control Input and $V_{EE}$ for Switch I/O)	$V_{in}$ , $V_{out}$	-0.5 to $V_{DD}$ + 0.5	V
Input Current (DC or Transient), per Control Pin	$I_{in}$	$\pm 10$	mA
Switch Through Current	$I_{sw}$	$\pm 25$	mA
Power Dissipation, per Package (Note 1)	$P_D$	500	mW
Ambient Temperature Range	$T_A$	-55 to + 125	°C
Storage Temperature Range	$T_{stg}$	-65 to + 150	°C
Lead Temperature (8-Second Soldering)	$T_L$	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. Operating the device outside its recommended conditions, but still within its maximum rated limits may not cause immediate damage. However, doing so can lead to reduced performance, unpredictable behavior, and potentially shorten the device's lifespan or reliability.

1. Temperature Derating: "D/DW" Package: -7.0 mW/°C From 65 °C To 125 °C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$  for control inputs and  $V_{EE} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$  for Switch I/O.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$ ,  $V_{EE}$  or  $V_{DD}$ ). Unused outputs must be left open.

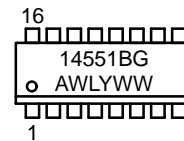


SOIC-16  
D SUFFIX  
CASE 751B

### PIN ASSIGNMENT

W1	1	16	$V_{DD}$
X0	2	15	W0
X1	3	14	W
X	4	13	Z
Y	5	12	Z1
Y0	6	11	Z0
$V_{EE}$	7	10	Y1
$V_{SS}$	8	9	CONTROL

### MARKING DIAGRAM

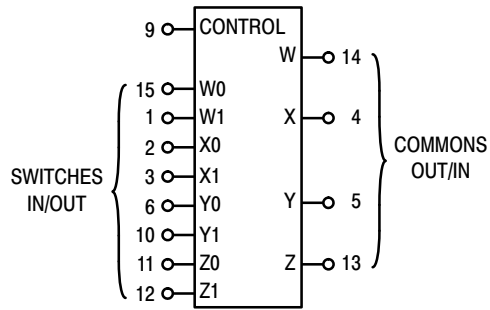


A = Assembly Location  
WL, L = Wafer Lot  
YY, Y = Year  
WW, W = Work Week  
G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# MC14551B



$V_{DD}$  = Pin 16  
 $V_{SS}$  = Pin 8  
 $V_{EE}$  = Pin 7

Control	ON
0	W0 X0 Y0 Z0
1	W1 X1 Y1 Z1

NOTE: Control Input referenced to  $V_{SS}$ . Analog Inputs and Outputs reference to  $V_{EE}$ .  $V_{EE}$  must be  $\leq V_{SS}$ .

## ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MC14551BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14551BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14551BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

\* NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

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## ELECTRICAL CHARACTERISTICS

Characteristic	V <sub>DD</sub>	Test Conditions	Symbol	–55 °C		25 °C			125 °C		Unit
				Min	Max	Min	Typ (Note 2)	Max	Min	Max	
SUPPLY REQUIREMENTS (Voltages Referenced to V <sub>EE</sub> )											
Power Supply Voltage Range	–	V <sub>DD</sub> – 3.0 ≥ V <sub>SS</sub> ≥ V <sub>EE</sub>	V <sub>DD</sub>	3.0	18	3.0	–	18	3.0	18	V
Quiescent Current Per Package	5.0 10 15	Control Inputs: V <sub>in</sub> = V <sub>SS</sub> or V <sub>DD</sub> , Switch I/O: V <sub>EE</sub> ≤ V <sub>I/O</sub> ≤ V <sub>DD</sub> , and ΔV <sub>switch</sub> ≤ 500 mV (Note 3)	I <sub>DD</sub>	– – –	5.0 10 20	– – –	0.005 0.010 0.015	5.0 10 20	– – –	150 300 600	μA
Total Supply Current (Dynamic Plus Quiescent, Per Package)	5.0 10 15	T <sub>A</sub> = 25 °C only (The channel component, (V <sub>in</sub> – V <sub>out</sub> )/R <sub>on</sub> , is not included.)	I <sub>D(AV)</sub>	Typical (0.07 μA/kHz) f + I <sub>DD</sub> (0.20 μA/kHz) f + I <sub>DD</sub> (0.36 μA/kHz) f + I <sub>DD</sub>							μA
CONTROL INPUT (Voltages Referenced to V <sub>SS</sub> )											
Low-Level Input Voltage	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	V <sub>IL</sub>	– – –	1.5 3.0 4.0	– – –	2.25 4.50 6.75	1.5 3.0 4.0	– – –	1.5 3.0 4.0	V
High-Level Input Voltage	5.0 10 15	R <sub>on</sub> = per spec, I <sub>off</sub> = per spec	V <sub>IH</sub>	3.5 7.0 11	– – –	3.5 7.0 11	2.75 5.50 8.25	– – –	3.5 7.0 11	– – –	V
Input Leakage Current	15	V <sub>in</sub> = 0 or V <sub>DD</sub>	I <sub>in</sub>	–	±0.1	–	±0.00001	±0.1	–	±1.0	μA
Input Capacitance	–		C <sub>in</sub>	–	–	–	5.0	7.5	–	–	pF
SWITCHES IN/OUT AND COMMONS OUT/IN — W, X, Y, Z (Voltages Referenced to V <sub>EE</sub> )											
Recommended Peak-to-Peak Voltage Into or Out of the Switch	–	Channel On or Off	V <sub>I/O</sub>	0	V <sub>DD</sub>	0	–	V <sub>DD</sub>	0	V <sub>DD</sub>	V <sub>p-p</sub>
Recommended Static or Dynamic Voltage Across the Switch (Note 3) (Figure 3)	–	Channel On	ΔV <sub>switch</sub>	0	600	0	–	600	0	300	mV
Output Offset Voltage	–	V <sub>in</sub> = 0 V, No Load	V <sub>OO</sub>	–	–	–	10	–	–	–	μV
ON Resistance	5.0 10 15	ΔV <sub>switch</sub> ≤ 500 mV (Note 3), V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> (Control), and V <sub>in</sub> = 0 to V <sub>DD</sub> (Switch)	R <sub>on</sub>	– – –	800 400 220	– – –	250 120 80	1050 500 280	– – –	1200 520 300	Ω
ΔON Resistance Between Any Two Channels in the Same Package	5.0 10 15		ΔR <sub>on</sub>	– – –	70 50 45	– – –	25 10 10	70 50 45	– – –	135 95 65	Ω
Off-Channel Leakage Current (Figure 8)	15	V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub> (Control) Channel to Channel or Any One Channel	I <sub>off</sub>	–	±100	–	±0.05	±100	–	±1000	nA
Capacitance, Switch I/O	–	Switch Off	C <sub>I/O</sub>	–	–	–	10	–	–	–	pF
Capacitance, Common O/I	–		C <sub>O/I</sub>	–	–	–	17	–	–	–	pF
Capacitance, Feedthrough (Channel Off)	– –	Pins Not Adjacent Pins Adjacent	C <sub>I/O</sub>	– –	– –	– –	0.15 0.47	– –	– –	– –	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labeled "Typ" is not to be used for design purposes, but is intended as an indication of the IC's potential performance.
3. For voltage drops across the switch (ΔV<sub>switch</sub>) > 600 mV (> 300 mV at high temperature), excessive V<sub>DD</sub> current may be drawn; i.e. the current out of the switch may contain both V<sub>DD</sub> and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded. (See first page of this data sheet.)

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## ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , $T_A = 25^\circ\text{C}$ , $V_{EE} \leq V_{SS}$ )

Characteristic	Symbol	$V_{DD} - V_{EE}$ $V_{dc}$	Min	Typ (Note 4)	Max	Unit
Propagation Delay Times Switch Input to Switch Output ( $R_L = 10 \text{ k}\Omega$ ) $t_{PLH}, t_{PHL} = (0.17 \text{ ns/pF}) C_L + 26.5 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.08 \text{ ns/pF}) C_L + 11 \text{ ns}$ $t_{PLH}, t_{PHL} = (0.06 \text{ ns/pF}) C_L + 9.0 \text{ ns}$	$t_{PLH}, t_{PHL}$	5.0 10 15	–	35 15 12	90 40 30	ns
Control Input to Output ( $R_L = 10 \text{ k}\Omega$ ) $V_{EE} = V_{SS}$ (Figure 4)	$t_{PLH}, t_{PHL}$	5.0 10 15	–	350 140 100	875 350 250	ns
Second Harmonic Distortion $R_L = 10 \text{ k}\Omega$ , $f = 1 \text{ kHz}$ , $V_{in} = 5 V_{p-p}$	–	10	–	0.07	–	%
Bandwidth (Figure 5) $R_L = 1 \text{ k}\Omega$ , $V_{in} = 1/2 (V_{DD} - V_{EE})_{p-p}$ , $20 \text{ Log } (V_{out}/V_{in}) = -3 \text{ dB}$ , $C_L = 50 \text{ pF}$	BW	10	–	17	–	MHz
Off Channel Feedthrough Attenuation, Figure 5 $R_L = 1 \text{ k}\Omega$ , $V_{in} = 1/2 (V_{DD} - V_{EE})_{p-p}$ , $f_{in} = 55 \text{ MHz}$	–	10	–	–50	–	dB
Channel Separation (Figure 6) $R_L = 1 \text{ k}\Omega$ , $V_{in} = 1/2 (V_{DD} - V_{EE})_{p-p}$ , $f_{in} = 3 \text{ MHz}$	–	10	–	–50	–	dB
Crosstalk, Control Input to Common O/I, Figure 7 $R_1 = 1 \text{ k}\Omega$ , $R_L = 10 \text{ k}\Omega$ , Control $t_r = t_f = 20 \text{ ns}$	–	10	–	75	–	mV

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

# MC14551B

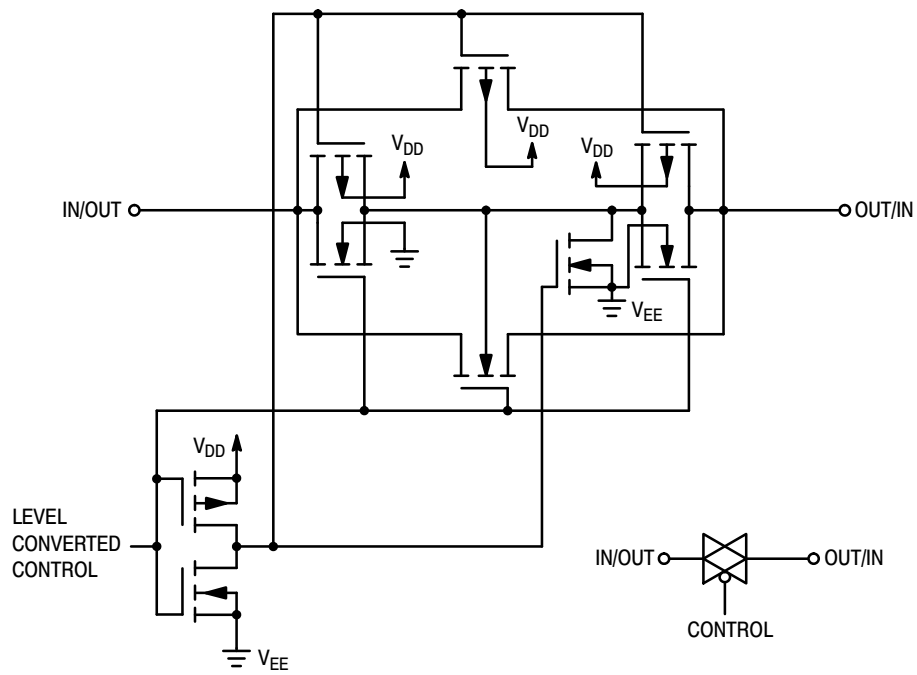


Figure 1. Switch Circuit Schematic

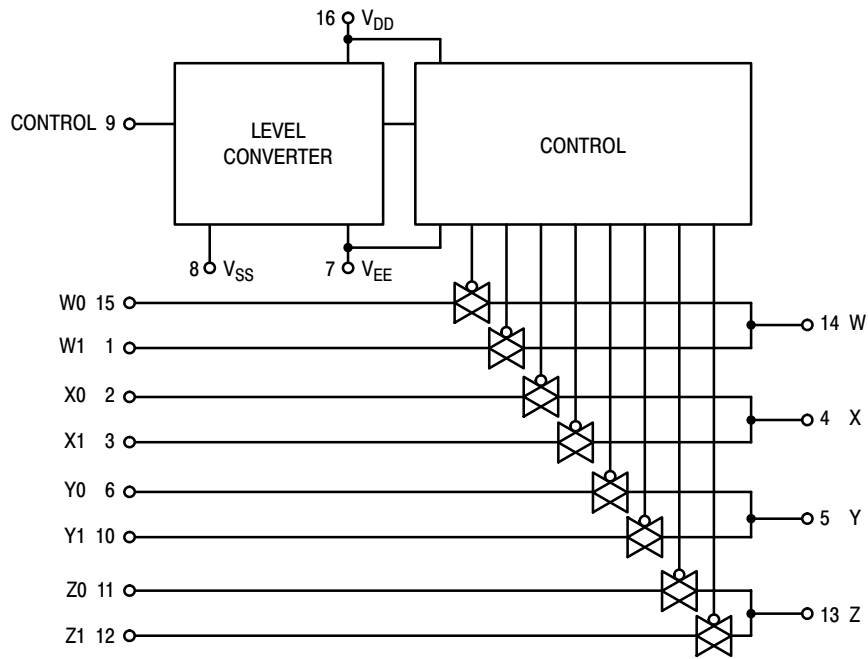


Figure 2. MC14551B Functional Diagram

TEST CIRCUITS

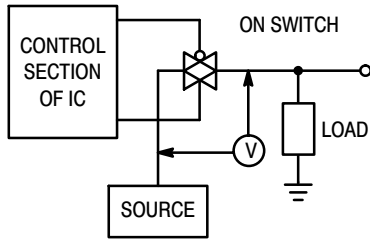


Figure 3.  $\Delta V$  Across Switch

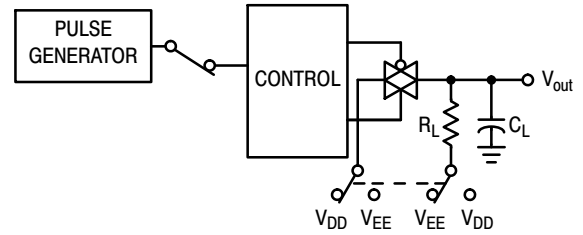


Figure 4. Propagation Delay Times, Control to Output

Control input used to turn ON or OFF the switch under test.

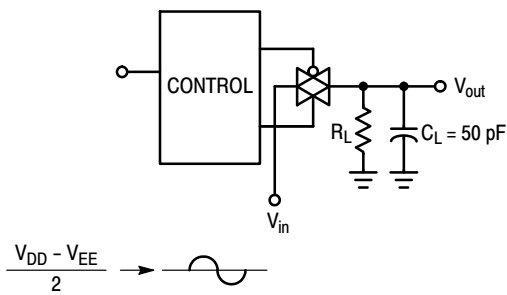


Figure 5. Bandwidth and Off-Channel Feedthrough Attenuation

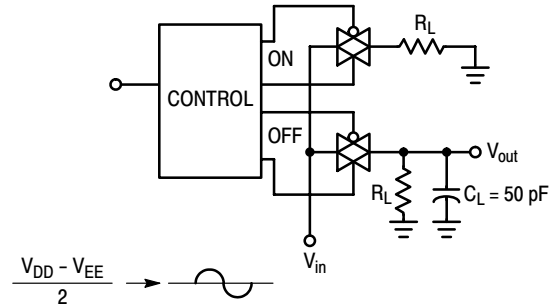


Figure 6. Channel Separation (Adjacent Channels Used for Setup)

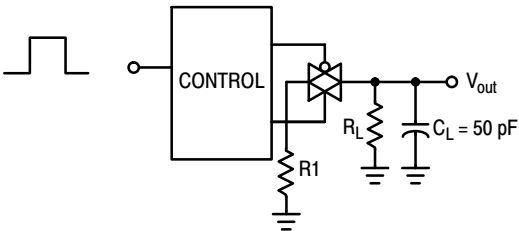


Figure 7. Crosstalk, Control Input to Common O/I

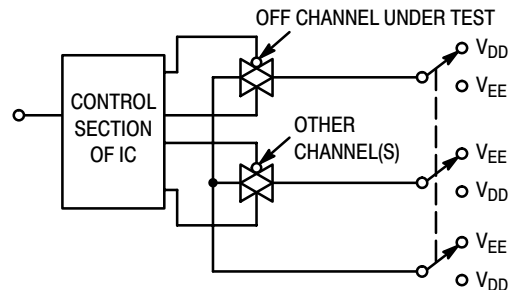


Figure 8. Off Channel Leakage

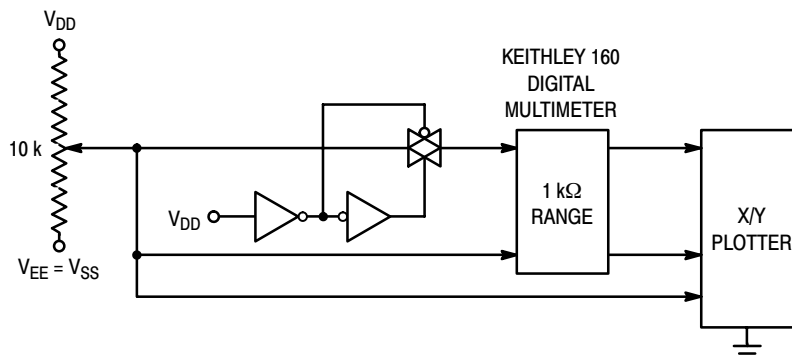
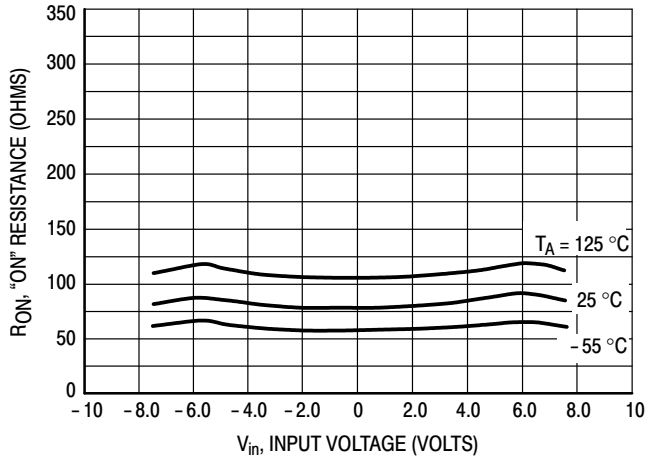
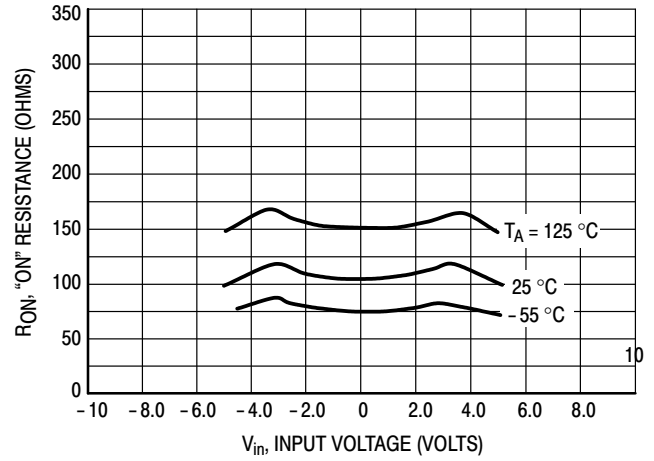
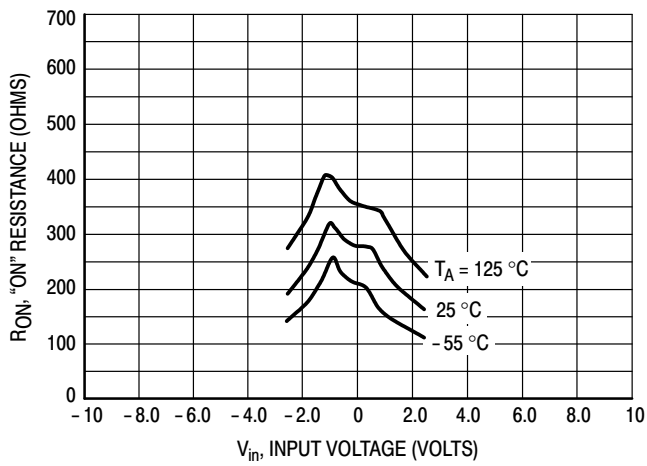
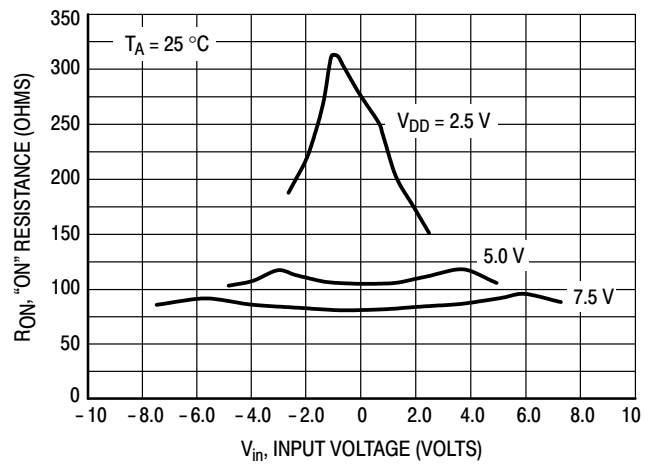


Figure 9. Channel Resistance ( $R_{ON}$ ) Test Circuit

## TYPICAL RESISTANCE CHARACTERISTICS

Figure 10.  $V_{DD}$  @ 7.5 V,  $V_{EE}$  @ -7.5 VFigure 11.  $V_{DD}$  @ 5.0 V,  $V_{EE}$  @ -5.0 VFigure 12.  $V_{DD}$  @ 2.5 V,  $V_{EE}$  @ -2.5 VFigure 13. Comparison at 25 °C,  $V_{DD}$  @ -  $V_{EE}$

## APPLICATIONS INFORMATION

Figure A illustrates use of the on-chip level converter detailed in Figure 2. The 0-to-5.0 V Digital Control signal is used to directly control a 9 V<sub>p-p</sub> analog signal.

The digital control logic levels are determined by V<sub>DD</sub> and V<sub>SS</sub>. The V<sub>DD</sub> voltage is the logic high voltage; the V<sub>SS</sub> voltage is logic low. For the example, V<sub>DD</sub> = +5.0 V = logic high at the control inputs; V<sub>SS</sub> = GND = 0 V = logic low.

The maximum analog signal level is determined by V<sub>DD</sub> and V<sub>EE</sub>. The V<sub>DD</sub> voltage determines the maximum recommended peak above V<sub>SS</sub>. The V<sub>EE</sub> voltage determines the maximum swing below V<sub>SS</sub>. For the example, V<sub>DD</sub> - V<sub>SS</sub> = 5.0 V maximum swing above V<sub>SS</sub>; V<sub>SS</sub> - V<sub>EE</sub> = 5.0 V maximum swing below V<sub>SS</sub>. The example shows a ±4.5 V

signal which allows a 1/2 V margin at each peak. If voltage transients above V<sub>DD</sub> and/or below V<sub>EE</sub> are anticipated on the analog channels, external diodes (D<sub>x</sub>) are recommended as shown in Figure B. These diodes should be small signal types able to absorb the maximum anticipated current surges during clipping.

The absolute maximum potential difference between V<sub>DD</sub> and V<sub>EE</sub> is 18 V. Most parameters are specified up to 15 V which is the recommended maximum difference between V<sub>DD</sub> and V<sub>EE</sub>.

Balanced supplies are not required. However, V<sub>SS</sub> must be greater than or equal to V<sub>EE</sub>. For example, V<sub>DD</sub> = +10 V, V<sub>SS</sub> = +5.0 V, and V<sub>EE</sub> = -3.0 V is acceptable. See the table below.

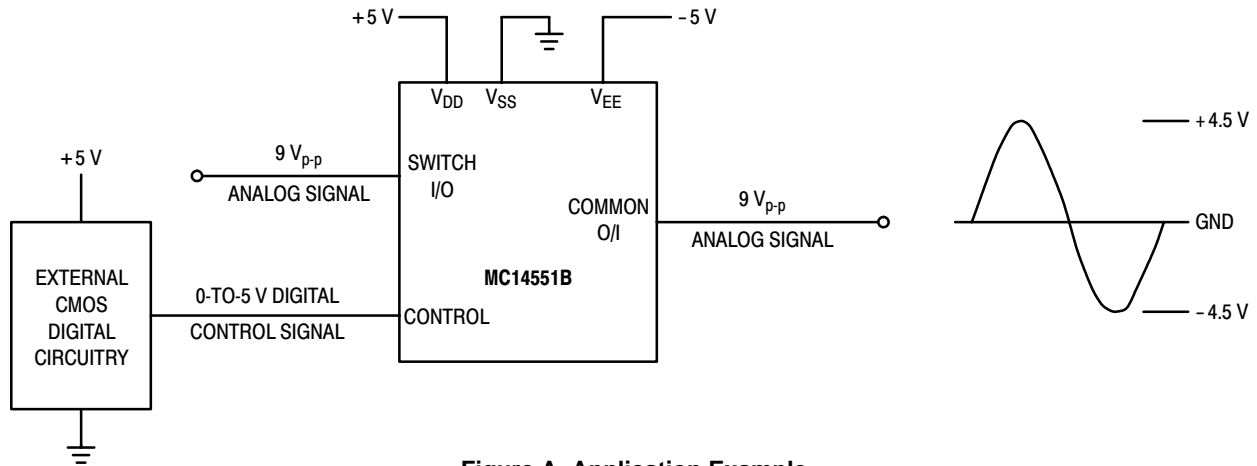


Figure A. Application Example



Figure B. External Schottky or Germanium Clipping Diodes

## POSSIBLE SUPPLY CONNECTIONS

V <sub>DD</sub> In Volts	V <sub>SS</sub> In Volts	V <sub>EE</sub> In Volts	Control Inputs Logic High/Logic Low In Volts	Maximum Analog Signal Range In Volts
+ 8	0	-8	+ 8/0	+ 8 to -8 = 16 V <sub>p-p</sub>
+ 5	0	-12	+ 5/0	+ 5 to -12 = 17 V <sub>p-p</sub>
+ 5	0	0	+ 5/0	+ 5 to 0 = 5 V <sub>p-p</sub>
+ 5	0	-5	+ 5/0	+ 5 to -5 = 10 V <sub>p-p</sub>
+ 10		-5	+ 10/ + 5	+ 10 to -5 = 15 V <sub>p-p</sub>

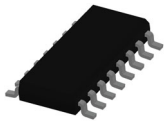


## MC14551B

### REVISION HISTORY

Revision	Description of Changes	Date
10	Rebranded the Data Sheet to <b>onsemi</b> format.	10/7/2025

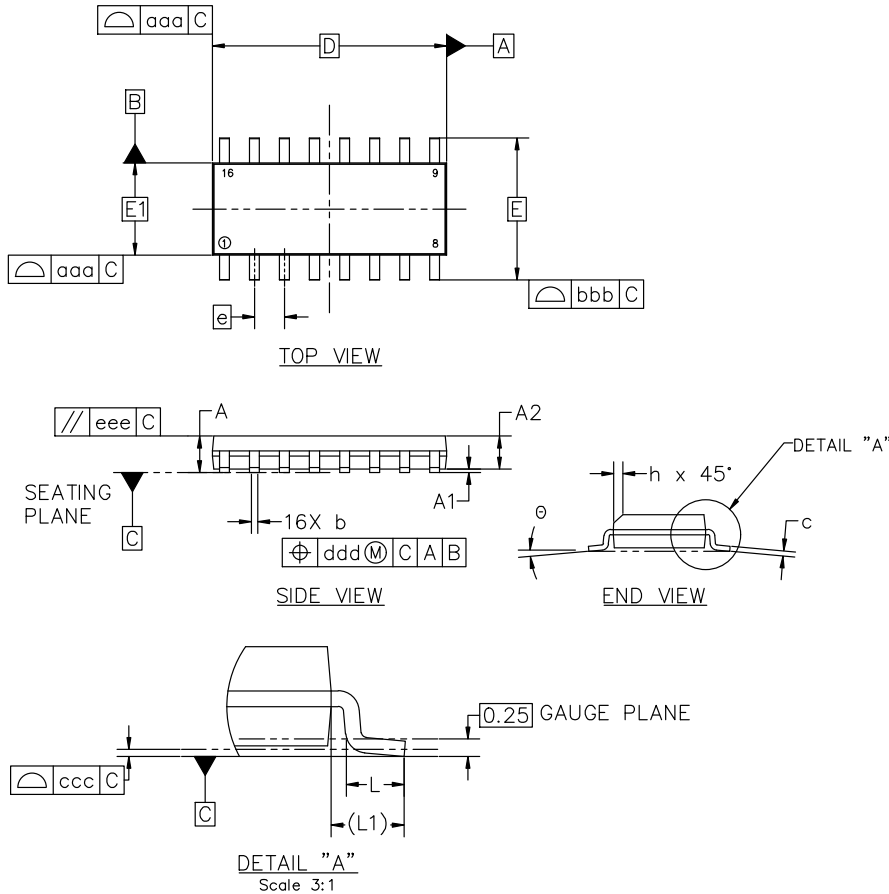
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.


**SOIC-16 9.90x3.90x1.37 1.27P**  
**CASE 751B**  
**ISSUE M**

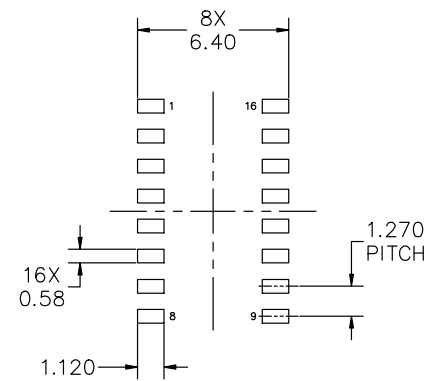
DATE 18 OCT 2024

## NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. DIMENSION IN MILLIMETERS. ANGLE IN DEGREES.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15mm PER SIDE.
5. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127mm TOTAL IN EXCESS OF THE b DIMENSION AT MAXIMUM MATERIAL CONDITION.



MILLIMETERS			
DIM	MIN	NOM	MAX
A	1.35	1.55	1.75
A1	0.10	0.18	0.25
A2	1.25	1.37	1.50
b	0.35	0.42	0.49
c	0.19	0.22	0.25
D	9.90 BSC		
E	6.00 BSC		
E1	3.90 BSC		
e	1.27 BSC		
h	0.25	---	0.50
L	0.40	0.83	1.25
L1	1.05 REF		
θ	0°	---	7°
TOLERANCE OF FORM AND POSITION			
aaa	0.10		
bbb	0.20		
ccc	0.10		
ddd	0.25		
eee	0.10		



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PB-FREE STRATEGY AND SOLDERING DETAILS,  
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AND MOUNTING TECHNIQUES REFERENCE  
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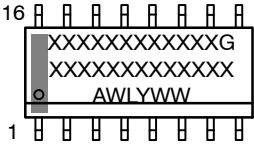
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<b>DESCRIPTION:</b>	<b>SOIC-16 9.90X3.90X1.37 1.27P</b>	<b>PAGE 1 OF 2</b>

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SOIC-16 9.90x3.90x1.37 1.27P  
CASE 751B  
ISSUE M

DATE 18 OCT 2024

GENERIC  
MARKING DIAGRAM\*



XXXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. COLLECTOR 2. BASE 3. EMITTER 4. NO CONNECTION 5. EMITTER 6. BASE 7. COLLECTOR 8. COLLECTOR 9. BASE 10. EMITTER 11. NO CONNECTION 12. EMITTER 13. BASE 14. COLLECTOR 15. EMITTER 16. COLLECTOR	STYLE 2: PIN 1. CATHODE 2. ANODE 3. NO CONNECTION 4. CATHODE 5. CATHODE 6. NO CONNECTION 7. ANODE 8. CATHODE 9. CATHODE 10. ANODE 11. NO CONNECTION 12. CATHODE 13. CATHODE 14. NO CONNECTION 15. ANODE 16. CATHODE	STYLE 3: PIN 1. COLLECTOR, DYE #1 2. BASE, #1 3. EMITTER, #1 4. COLLECTOR, #1 5. COLLECTOR, #2 6. BASE, #2 7. EMITTER, #2 8. COLLECTOR, #2 9. COLLECTOR, #3 10. BASE, #3 11. EMITTER, #3 12. COLLECTOR, #3 13. COLLECTOR, #4 14. BASE, #4 15. EMITTER, #4 16. COLLECTOR, #4	STYLE 4: PIN 1. COLLECTOR, DYE #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. COLLECTOR, #3 6. COLLECTOR, #3 7. COLLECTOR, #4 8. COLLECTOR, #4 9. BASE, #4 10. EMITTER, #4 11. BASE, #3 12. EMITTER, #3 13. BASE, #2 14. EMITTER, #2 15. BASE, #1 16. EMITTER, #1
STYLE 5: PIN 1. DRAIN, DYE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. DRAIN, #3 6. DRAIN, #3 7. DRAIN, #4 8. DRAIN, #4 9. GATE, #4 10. SOURCE, #4 11. GATE, #3 12. SOURCE, #3 13. GATE, #2 14. SOURCE, #2 15. GATE, #1 16. SOURCE, #1	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. CATHODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE 15. ANODE 16. ANODE	STYLE 7: PIN 1. SOURCE N-CH 2. COMMON DRAIN (OUTPUT) 3. COMMON DRAIN (OUTPUT) 4. GATE P-CH 5. COMMON DRAIN (OUTPUT) 6. COMMON DRAIN (OUTPUT) 7. COMMON DRAIN (OUTPUT) 8. SOURCE P-CH 9. SOURCE P-CH 10. COMMON DRAIN (OUTPUT) 11. COMMON DRAIN (OUTPUT) 12. COMMON DRAIN (OUTPUT) 13. GATE N-CH 14. COMMON DRAIN (OUTPUT) 15. COMMON DRAIN (OUTPUT) 16. SOURCE N-CH	

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